

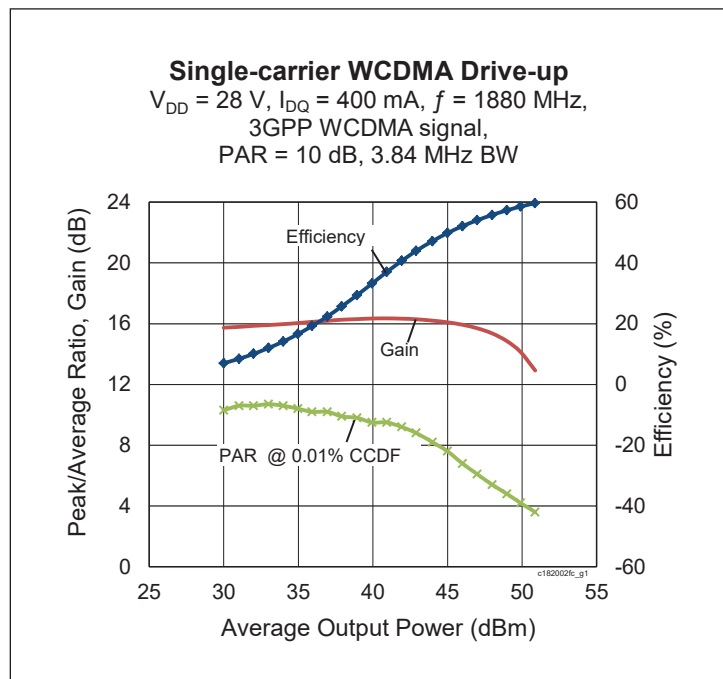
PXAC182002FC

Thermally-Enhanced High Power RF LDMOS FET 180 W, 28 V, 1805 – 1880 MHz

Description

The PXAC182002FC is a 180-watt LDMOS FET with an asymmetrical design intended for use in multi-standard cellular power amplifier applications in the 1805 to 1880 MHz frequency band. Features include dual-path design, input and output matching, high gain and thermally-enhanced package with earless flanges. Manufactured with Wolfspeed's advanced LDMOS process, this device provides excellent thermal performance and superior reliability.

PXAC182002FC
Package H-37248-4



Features

- Broadband internal input and output matching
- Asymmetrical Doherty design
 - Main: 70 W Typ (P_{1dB})
 - Peak: 110 W Typ (P_{1dB})
- Typical pulsed CW performance, 1880 MHz, 28 V, combined outputs
 - Output power at $P_{3dB} = 194\text{ W}$
 - Efficiency = 64%
 - Gain = 14 dB
- Capable of handling 10:1 VSWR @ 28 V, 110 W (CW) output power
- Integrated ESD protection
- Human Body Model Class 1C (per ANSI/ESDA/ JEDEC/JS-001)
- Low thermal resistance
- Pb-free and RoHS compliant

RF Characteristics

Single-carrier WCDMA Specifications (tested in Wolfspeed Doherty test fixture)

$V_{DD} = 28\text{ V}$, $I_{DQ} = 400\text{ mA}$, $V_{GSPEAK} = 1.1\text{ V}$, $P_{OUT} = 28.2\text{ W avg}$, $f = 1880\text{ MHz}$, 3GPP signal, channel bandwidth = 3.84 MHz, peak/average = 10 dB @ 0.01% CCDF

Characteristic	Symbol	Min	Typ	Max	Unit
Gain	G_{ps}	15.5	16.5	—	dB
Drain Efficiency	η_D	48.5	51	—	%
Adjacent Channel Power Ratio	ACPR	—	-30	-26	dBc

All published data at $T_{CASE} = 25^\circ\text{C}$ unless otherwise indicated

ESD: Electrostatic discharge sensitive device—observe handling precautions!

DC Characteristics (each side)

Characteristic	Conditions	Symbol	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_{DS} = 10\text{ mA}$	$V_{(BR)DSS}$	65	—	—	V
Drain Leakage Current	$V_{DS} = 28\text{ V}, V_{GS} = 0\text{ V}$	I_{DSS}	—	—	0.1	μA
	$V_{DS} = 63\text{ V}, V_{GS} = 0\text{ V}$	I_{DSS}	—	—	1.0	μA
On-State Resistance (main)	$V_{GS} = 10\text{ V}, V_{DS} = 0.1\text{ V}$	$R_{DS(on)}$	—	0.18	—	Ω
	(peak) $V_{GS} = 10\text{ V}, V_{DS} = 0.1\text{ V}$	$R_{DS(on)}$	—	0.135	—	Ω
Operating Gate Voltage (main)	$V_{DS} = 28\text{ V}, I_{DQ} = 400\text{ mA}$	V_{GS}	2.55	2.65	2.75	V
	(peak) $V_{DS} = 28\text{ V}, I_{DQ} = 0\text{ A}$	V_{GS}	0.9	1.2	1.3	V
Gate Leakage Current	$V_{GS} = 10\text{ V}, V_{DS} = 0\text{ V}$	I_{GSS}	—	—	0.1	μA

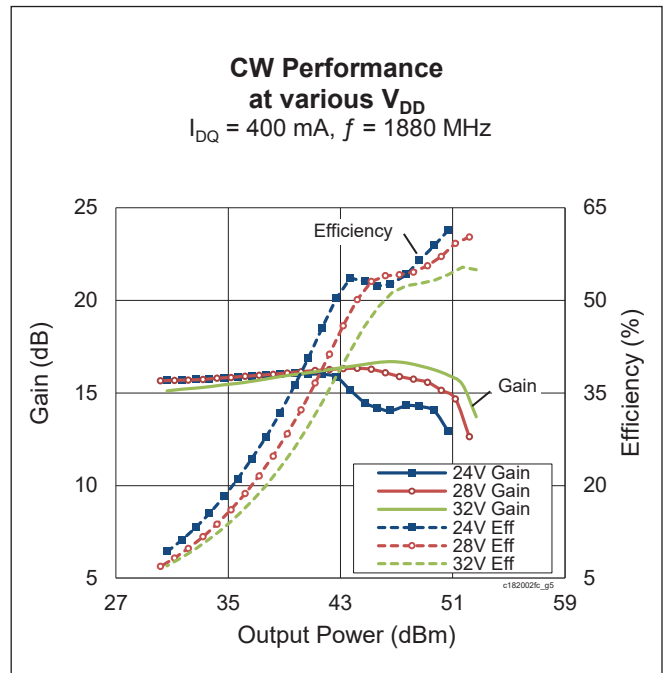
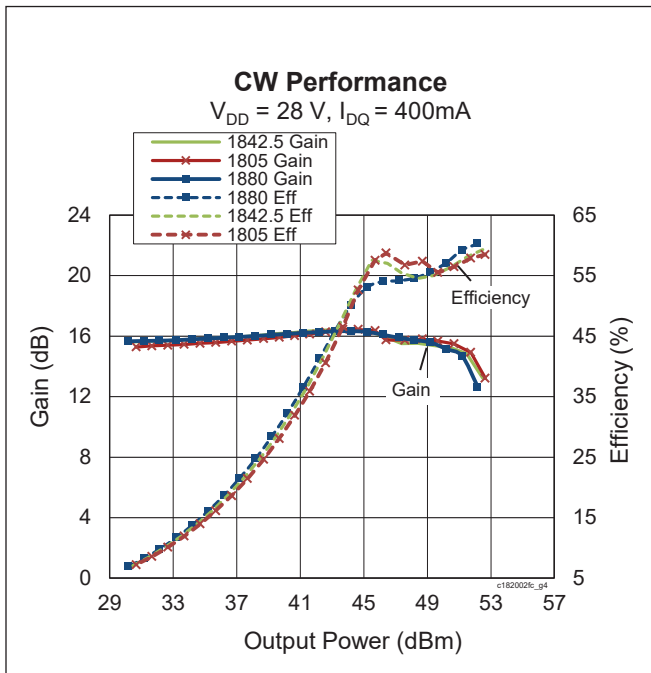
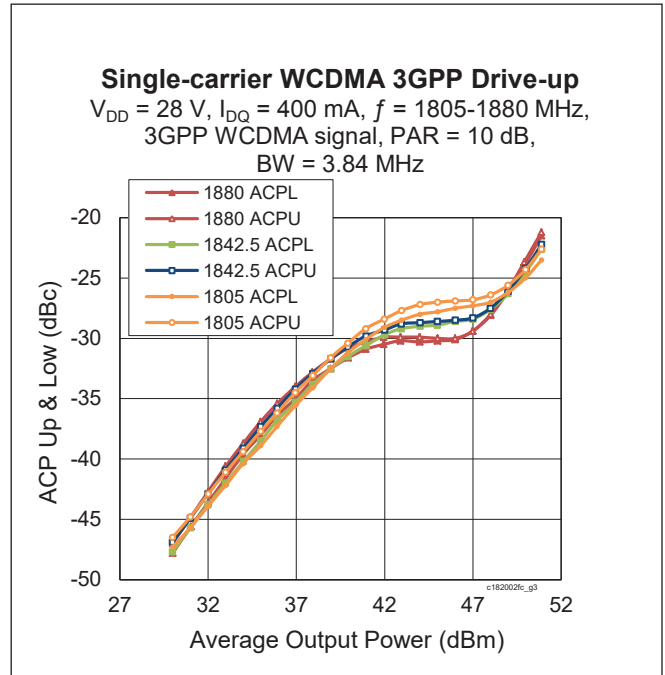
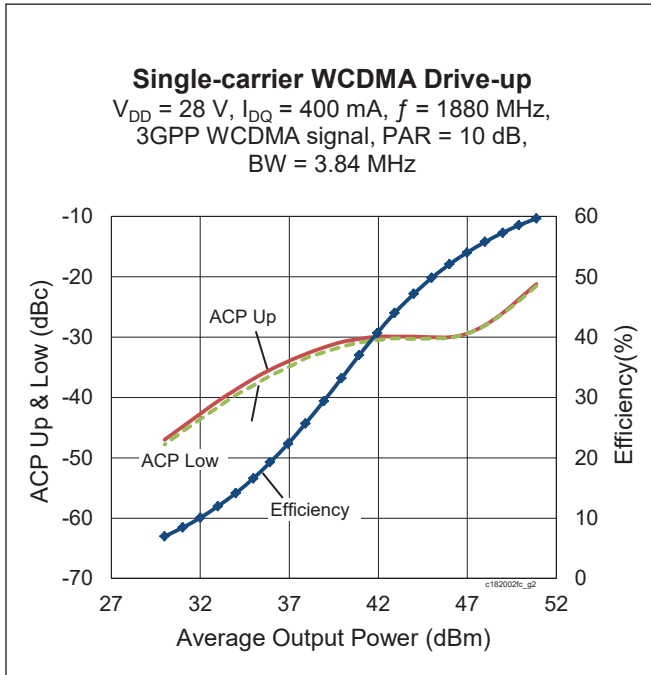
Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	65	V
Gate-Source Voltage	V_{GS}	-6 to +10	V
Operating Voltage	V_{DD}	0 to +32	V
Junction Temperature	T_J	225	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-65 to +150	$^{\circ}\text{C}$
Thermal Resistance (main, $T_{CASE} = 70^{\circ}\text{C}$, 28 W CW)	$R_{\theta JC}$	1.088	$^{\circ}\text{C}/\text{W}$
	(peak, $T_{CASE} = 70^{\circ}\text{C}$, 100 W CW)	$R_{\theta JC}$	0.587

Ordering Information

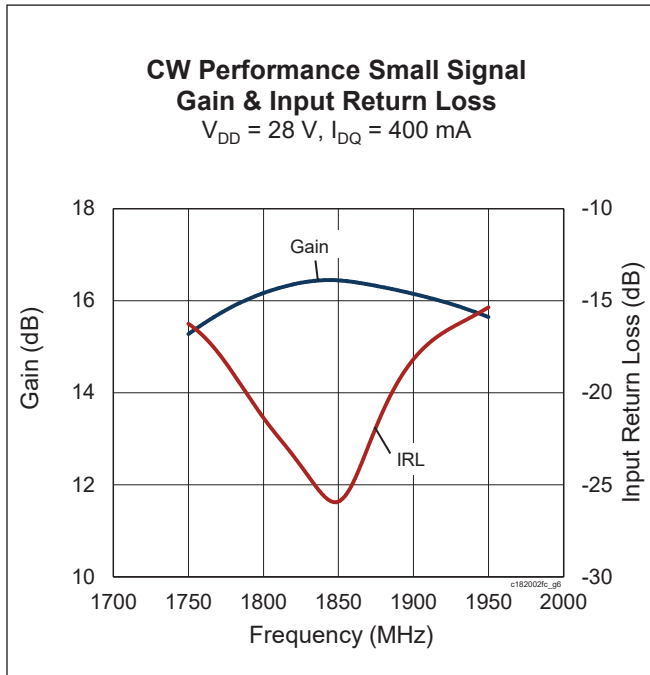
Type and Version	Order Code	Package Description	Shipping
PXAC182002FC V1 R0	PXAC182002FC-V1-R0	H-37248-4, earless flange	Tape & Reel, 50 pcs
PXAC182002FC V1 R250	PXAC182002FC-V1-R250	H-37248-4, earless flange	Tape & Reel, 250 pcs

Typical Performance (data taken in a production test fixture)





Typical Performance (cont.)



Load Pull Performance

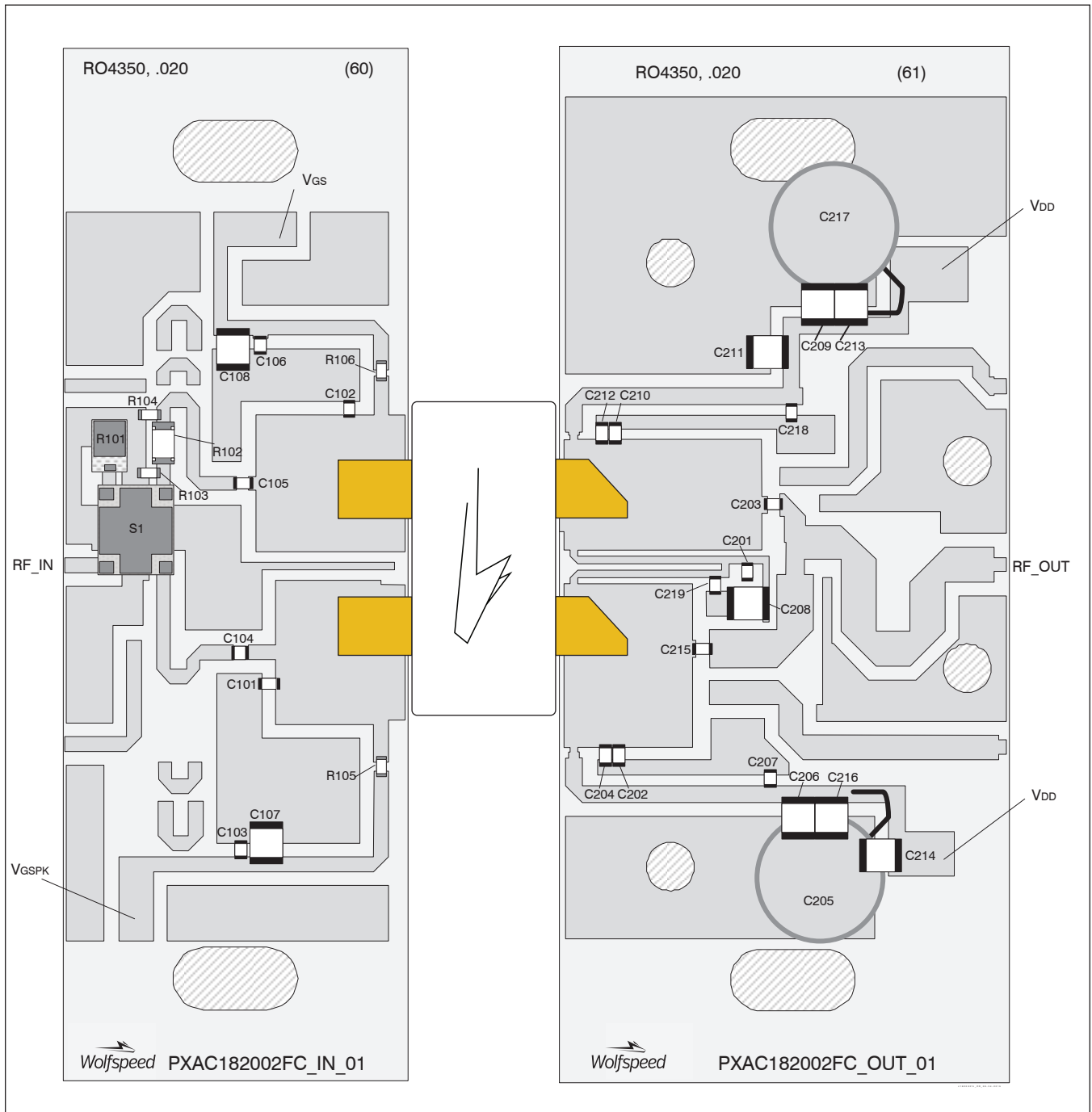
Main Side Load Pull Performance – Pulsed CW signal: 160 μs , 10% duty cycle, 28 V, $I_{DQ} = 405\text{ mA}$

		P_{1dB}									
		Max Output Power					Max Drain Efficiency				
Freq [MHz]	Z_s [Ω]	Z_l [Ω]	Gain [dB]	P_{OUT} [dBm]	P_{OUT} [W]	η_D [%]	Z_l [Ω]	Gain [dB]	P_{OUT} [dBm]	P_{OUT} [W]	η_D [%]
1810	3.94 – j10.15	2.92 – j5.27	19.2	49.4	86	54.0	6.49 – j2.19	21.9	47.2	52	66.6
1840	5.13 – j10.93	2.93 – j4.16	19.5	49.3	85	57.6	5.82 – j2.44	21.7	47.5	56	66.3
1880	5.90 – j12.44	2.73 – j5.17	19.2	49.5	89	55.2	4.53 – j2.29	21.5	47.7	59	67.9

Peak Side Load Pull Performance – Pulsed CW signal: 160 μs , 10% duty cycle, 28 V, $I_{DQ} = 685\text{ mA}$

		P_{1dB}									
		Max Output Power					Max Drain Efficiency				
Freq [MHz]	Z_s [Ω]	Z_l [Ω]	Gain [dB]	P_{OUT} [dBm]	P_{OUT} [W]	η_D [%]	Z_l [Ω]	Gain [dB]	P_{OUT} [dBm]	P_{OUT} [W]	η_D [%]
1810	3.71 – j9.13	4.64 – j5.44	20.5	50.9	123	55.5	3.52 – j2.84	22.7	49.7	94	66.2
1840	4.76 – j8.65	4.66 – j5.68	20.6	50.7	117	54.5	3.39 – j3.01	23.2	49.2	84	64.1
1880	6.40 – j9.13	4.63 – j5.74	20.8	50.7	116	54.3	2.83 – j3.50	23.1	49.2	83	64.3

Reference Circuit , 1805 – 1880 MHz



Reference circuit assembly diagram (not to scale)



Reference Circuit (cont.)

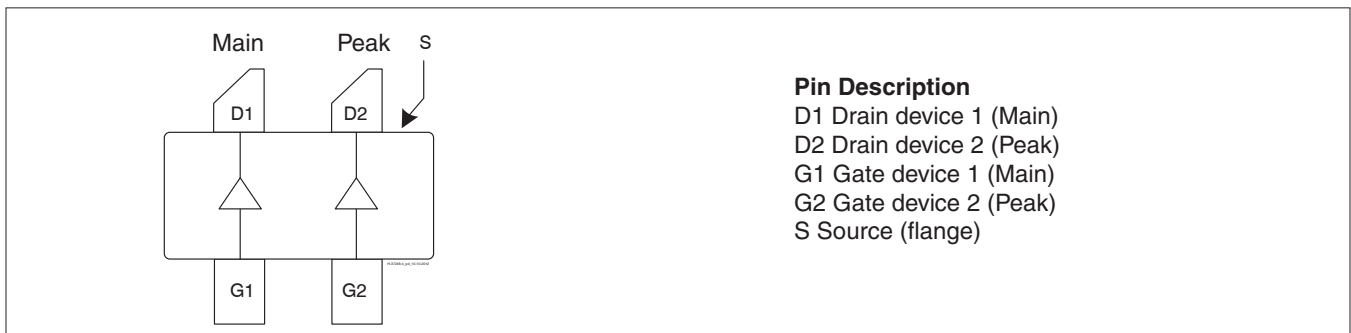
Reference Circuit Assembly

DUT	PXAC182002FC V1
Test Fixture Part No.	LTA/PXAC182002FC V1
PCB	Rogers 4350, 0.508 mm [0.020"] thick, 2 oz. copper, $\epsilon_r = 3.66$, $f = 1805 - 1880$ MHz
Find Gerber files for this test fixture on the Wolfspeed Web site at www.wolfspeed.com/RF	

Components Information

Component	Description	Manufacturer	P/N
Input			
C101	Capacitor, 1.2 pF	ATC	ATC600F1R2CW250T
C102	Capacitor, 0.5 pF	ATC	ATC600F0R5CW250T
C103, C104, C105, C106	Capacitor, 18 pF	ATC	ATC600F180JW250T
C107, C108	Capacitor, 10 μ F	Taiyo Yuden	UMK325C7106MM-T
R101	Resistor, 50 Ω	Richardson	C8A50Z4A
R102	Resistor, 18 ohms	Panasonic Electronic Components	ERJ-8GEYJ180V
R103, R104	Resistor, 301 Ω	Venkel	CR0603-16W-3010FT
R105, R106	Resistor, 10 Ω	Panasonic Electronic Components	ERJ-3GEYJ100V
S1	Hybrid Coupler	Anaren	X3C19P1-03S
Output			
C201, C207, C215, C218, C219	Capacitor, 18 pF	ATC	ATC600F180JW250T
C202	Capacitor, 0.8 pF	ATC	ATC600F0R8AW250T
C203	Capacitor, 5.1 pF	ATC	ATC600F5R1AW250T
C204	Capacitor, 1.6 pF	ATC	ATC600F1R6AW250T
C205, C217	Capacitor, 220 μ F	Cornell Dubilier Electronics	SK221M050ST
C206, C208, C209, C211, C213, C214, C216	Capacitor, 10 μ F	Taiyo Yuden	UMK325C7106MM-T
C210	Capacitor, 0.5 pF	ATC	ATC600F0R5AW250T
C212	Capacitor, 1.6 pF	ATC	ATC600F1R6AW250T

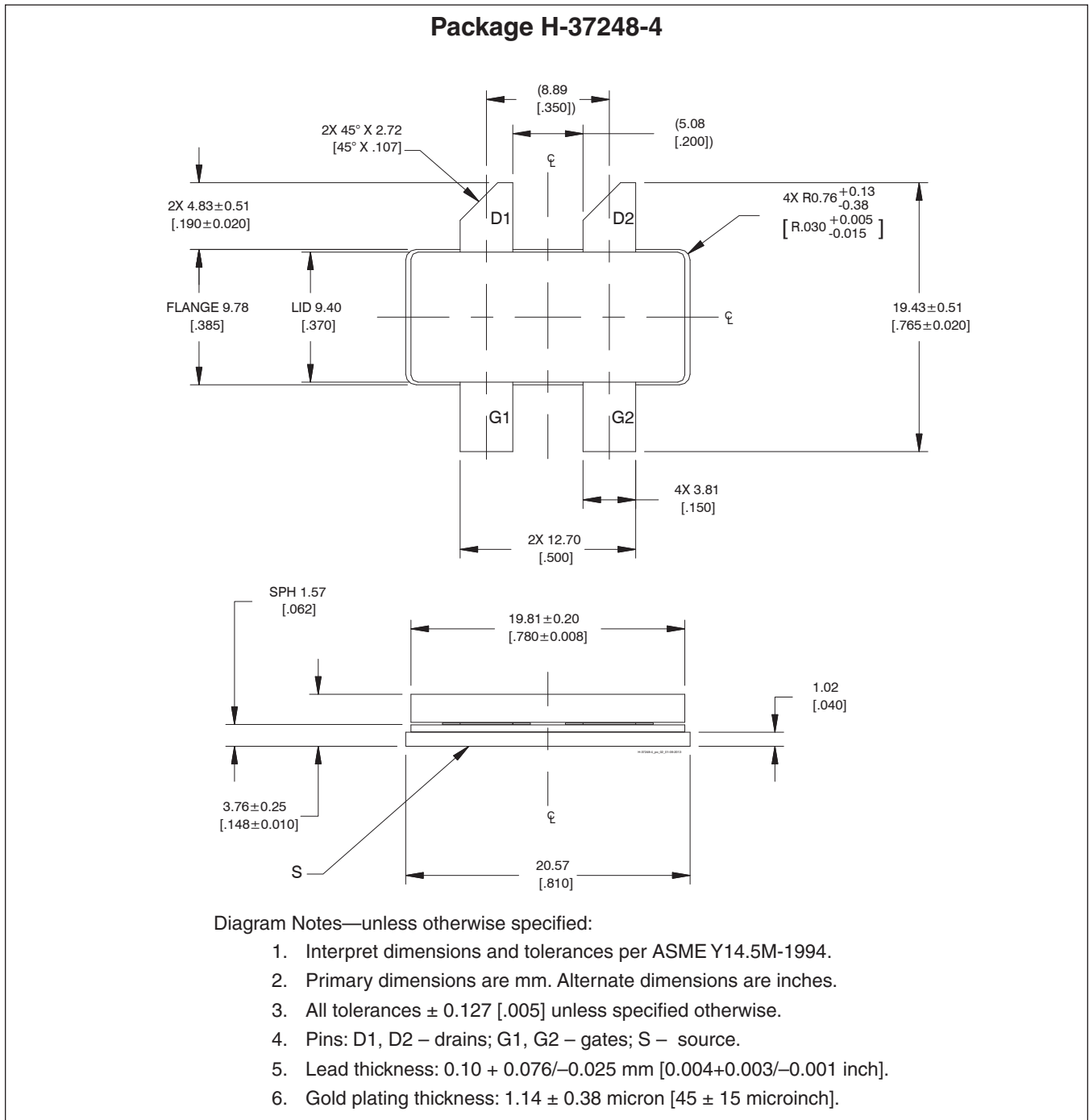
Pinout Diagram (top view)



Pin Description
 D1 Drain device 1 (Main)
 D2 Drain device 2 (Peak)
 G1 Gate device 1 (Main)
 G2 Gate device 2 (Peak)
 S Source (flange)

Lead connections for PXAC182002FC

Package Outline Specifications



Revision History

Revision	Date	Data Sheet Type	Page	Subjects (major changes since last revision)
01	2014-09-23	Advance	All	Data Sheet reflects advance specification for product development
02	2015-03-24	Production	All All	Data Sheet reflects released product specification Revised all data and includes updated final specs, typical performance graphs, loadpull, reference circuit, package outline
02.1	2015-05-20	Production	1	Updated single-carrier WCDMA test spec
02.2	2015-06-05	Production	1	Corrected I/O in description paragraph, removed f_1 from single-carrier WCDMA test spec condition
02.3	2016-06-17	Production	1, 2	Updated ESD rating and ordering information to include R0
03	2018-06-25	Production	All	Converted to Wolfspeed Data Sheet

For more information, please contact:

4600 Silicon Drive
Durham, North Carolina, USA 27703
www.wolfspeed.com/RF

Sales Contact
RFSales@wolfspeed.com

RF Product Marketing Contact
RFMarketing@wolfspeed.com
919.407.7816

Notes

Disclaimer

Specifications are subject to change without notice. Cree, Inc. believes the information contained within this data sheet to be accurate and reliable. However, no responsibility is assumed by Cree for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Cree. Cree makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose. "Typical" parameters are the average values expected by Cree in large quantities and are provided for information purposes only. These values can and do vary in different applications and actual performance can vary over time. All operating parameters should be validated by customer's technical experts for each application. Cree products are not designed, intended or authorized for use as components in applications intended for surgical implant into the body or to support or sustain life, in applications in which the failure of the Cree product could result in personal injury or death or in applications for planning, construction, maintenance or direct operation of a nuclear facility.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.